

General Description

The AOZ5239QI is a high efficiency synchronous buck power stage module consisting of two asymmetrical MOSFETs and an integrated driver. The MOSFETs are individually optimized for operation in the synchronous buck configuration. The high side MOSFET is optimized to achieve low capacitance and gate charge for fast switching with low duty cycle operation. The low side MOSFET has ultra low ON resistance to minimize conduction loss. The compact 5x5 QFN package is optimally designed to minimize parasitic inductance for minimal EMI signature.

The AOZ5239QI is compatible with 3.3V and 5V PWM logic with Mid-state levels compatibility by using both the PWM and/or SMOD# can be used to control the power MOSFETs.

The bootstrap diode is integrated in the driver. The low side MOSFET can be driven into pulse skip mode to provide power saving operation when required. The pinout is optimized for low inductance routing, keeping the parasitics and their effects to a minimum.

Features

- 4.5V to 25V power supply range
- 4.5V to 5.5V driver supply range
- Up to 70A peak output current
- Continuous current up to 50A
- **Integrated booststrap schottky diode**
- Up to 2MHz switching operation
- Pulse Skip Mode for Light Load Efficiency
- Supports Intel ® Power State 4
- **Thermal Warning Output**
- **Thermal Shutdown**
- **Tri-state PWM input compatible**
- Under-Voltage LockOut protection
- **.** Low Profile 5x5 QFN-31L package

Applications

- **•** Desktop
- Notebook computers
- Graphic cards
- Video gaming console

Typical Application Circuit

Ordering Information

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Please visit [www.aosmd.com/media/AOSGreenPolicy.pdf](http://www.aosmd.com/web/quality/rohs_compliant.jsp) for additional information.

Pin Configuration

Pin Description

Functional Block Diagram

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Notes:

- 1. Peak voltages can be applied for 5ns per switching cycle.
- 2. Devices are inherently ESD sensitive, handling precautions are required. Human body model rating: $1.5 \text{k}\Omega$ in series with 100pF.

Recommended Operating Conditions

The device is not guaranteed to operate beyond the Maximum Recommended Operating Conditions.

Electrical Characteristics(3)

 $T_A = 25^{\circ}$ C, V_{IN} = 12V, P_{VCC} = V_{CC} = 5V, V_{CC} = P_{VCC} = 1.0µF, DISB# = 2.0V, unless otherwise specified.

Electrical Characteristics(3)

 T_A = 25°C, V_{IN} = 12V, P_{VCC} = V_{CC} = 5V, V_{CC} = P_{VCC} = 1.0µF, DISB# = 2.0V, unless otherwise specified.

Notes:

3. All voltages are specified with respect to the corresponding PGND pin.

4. Characterization value. Not tested in production.

Table 1. Logic Table

Notes:

5. PWM input is driven to mid−state with internal divider resistors when SMOD# is driven to mid−state and PWM input is undriven externally.

6. GL goes low following 80 ns de−bounce time, 250 ns blanking time and then VSWH exceeding ZCD threshold.

7. There is no delay before GL goes low.

Timing Diagram

Figure 2. Tri-State Input Logic Timing Diagram(8)

Note:

8. If the Zero Current Detect circuit detects zero current after the ZCD Wait timer period, the GL is driven low by the Zero Current Detect signal. If the Zero Current Detect circuit detects zero current before the ZCD Wait timer period expires, the Zero Current detect signal is ignored and the GL is driven low at the end of the ZCD Wait timer period.

Figure 3. SMOD# Logic Timing Diagram(9)

Note:

9. If the SMOD# input is driven low at any time after the GL has been driven high, the SMOD# Falling edge triggers the GL to go low. If the SMOD# input is driven low while the GH is high, the SMOD# input is ignored.

Use with Controllers with 3-State PWM and No Zero Current Detection Capability:

Table 2. Logic Table: 3-State PWM Controllers with No Zero Cross Detect Function

This section describes operation with controllers that are capable of 3-states at their PWM output and relies on the AOZ5239QI to conduct zero current detection during discontinuous conduction mode (DCM).

The SMOD# pin needs to either be set to 5V or left disconnected. The SMOD# has an internal pull−up resistor that connects to VCC that sets SMOD# to the logic high state if this pin is disconnected.

To operate the buck converter in continuous conduction mode (CCM), PWM needs to switch between the logic high and low states. To enter into DCM, PWM needs to be switched to the mid−state (floating).

Whenever PWM transitions to mid−state, GH turns off and GL turns on (VSWH is pulled low). GL stays on for the duration of the de−bounce timer and ZCD blanking timers. Once these timers expire, the AOZ5239QI monitors the VSWH voltage and turns GL off when VSWH exceeds the ZCD threshold voltage. By turning off the LS MOSFET, the body diode of the LS MOSFET allows positive current to go to zero but prevents negative current conduction.

Figure 4. Timing Diagram: 3−state PWM Controller, No ZCD

Use with Controllers with 3-State PWM and Zero Current Detection Capability:

Table 3. Logic Table: 3-State PWM Controllers with ZCD

This section describes operation with controllers that are capable of 3 PWM output levels and have zero current detection during discontinuous conduction mode (DCM). The SMOD# pin needs to be pulled low (below VSMOD#_LO).

To operate the buck converter in continuous conduction mode (CCM), PWM needs to switch between the logic high and low states. During DCM, the controller is

responsible for detecting when zero current has occurred, and then notifying the AOZ5239QI to turn off the LS MOSFET. When the controller detects zero current, it needs to set PWM to mid−state, which causes the AOZ5239QI to pull both GH and GL to their off states without delay.

Figure 5. Timing Diagram: 3−state PWM Controller, with ZCD

Typical Performance Characteristics

 T_A = 25°C, V_{IN} = 12V, PV_{CC} = V_{CC} = 5V, unless otherwise specified.

Figure 8. UVLO Threshold vs. Temperature Figure 9. Supply Current vs. Switching Frequency

Typical Performance Characteristics

 T_A = 25°C, V_{IN} = 12V, PV_{CC} = V_{CC} = 5V, unless otherwise specified

Figure 12. PWM Threshold vs V_{CC} Figure 13. PWM Threshold vs. Temperature

Figure 14. PWM Input Resistance vs. Temperature

Theory of Operation

The AOZ5239QI is an integrated driver and MOSFET module designed for use in a synchronous buck converter topology. The AOZ5239QI supports numerous application control definitions including Pin Enable and alternately PWM Tristate Control. A PWM input signal is required to control the drive signals to the high−side and low−side integrated MOSFETs.

Low-Side Driver

The low−side driver drives an internal, ground− referenced low−RDS(on) N−Channel MOSFET. The voltage supply for the low−side driver is internally connected to the PVCC and PGND pins.

High-Side Driver

The high−side driver drives an internal, floating low−RDS(on) N−channel MOSFET. The gate voltage for the high side driver is developed by a bootstrap circuit referenced to Switch Node (VSWH, PHASE) pins.

The bootstrap circuit is comprised of the integrated diode and an external bootstrap capacitor and resistor. When the AOZ5239QI is starting up, the VSWH pin is at ground, allowing the bootstrap capacitor to charge up to PVCC through the bootstrap diode. When the PWM input is driven high, the high−side driver will turn on the high−side MOSFET using the stored charge of the bootstrap capacitor. As the high−side MOSFET turns on, the voltage at the VSWH and PHASE pins rise. When the high−side MOSFET is turned fully on, the switch node will settle to VIN and the BOOT pin will settle to VIN + PVCC (excluding parasitic ringing).

Bootstrap Circuit

The bootstrap circuit relies on an external charge storage capacitor (C_{BOOT}) and an integrated diode to provide current to the HS Driver. A multi−layer ceramic capacitor (MLCC) with a value greater than 100 nF should be used as the bootstrap capacitor. An optional 1 to $4Ω$ resistor in series with C_{BODT} is recommended to decrease VSWH overshoot.

Power Supply Decoupling

The AOZ5239QI will source relatively large currents into the MOSFET gates. In order to maintain a constant and stable supply voltage (PVCC), a low−ESR capacitor should be placed near the PGND pins. A multi layer ceramic capacitor (MLCC) between 1µF and 4.7µF is typically used.

A separate supply pin (VCC) is used to power the analog and digital circuits within the driver. A 1µF ceramic capacitor should be placed on this pin in close proximity to the AOZ5239QI. It is good practice to separate the VCC and PVCC decoupling capacitors with a resistor (10 Ω typical) to avoid coupling driver noise to the analog and digital circuits that control driver function (See Figure 1).

Safety Timer and Overlap Protection Circuit

It is important to avoid cross−conduction of the two MOSFETs which could result in a decrease in the power conversion efficiency or damage to the device.

The AOZ5239QI prevents cross conduction by monitoring the status of the MOSFET gates and applying the appropriate amount of non−overlap time (the time between the turn−off of one MOSFET and the turn−on of the other MOSFET). When the PWM input pin is driven high, the low−side MOSFET gate (GL) starts to go low after a propagation delay (t_{pdlGL}) . The time it takes for the low−side MOSFET to turn off is dependent on the low−side MOSFET gate charge. The high−side MOSFET source terminal (VSWH) begins to rise following a fixed time (tpdh_{VSWH}) after the GL voltage falls below the low−side MOSFET gate threshold.

When the PWM input pin is driven low, the LOW−side MOSFET drain terminal (VSWH) starts to go low after a propagation delay (tpdl $_{VSWH}$). The time it takes for the high−side MOSFET to turn off is dependent on the high−side MOSFET gate charge. The low−side MOSFET gate begins to rise after a fixed time (tpdh $_{GI}$) following the VSWH voltage falling edge below the 1V.

PWM Input

The PWM Input pin is a tri−state input used to control the HS MOSFET ON/OFF state. In conjunction with SMOD# pin, it also determines the state of the LS MOSFET. See Table1 for logic operation. The PWM in some cases must operate with frequency programming resistances to ground. These resistances can range from 10k to 300k depending on the application. When SMOD# is set to > VSMOD#_HI or to < VSMOD#_LO, the input impedance to the PWM input is very high in order to avoid interferences with controllers that must use programming resistances on the PWM pin. If SMOD# is set such that: VSMOD# LO < SMOD# < VSMOD# HI which means, SMOD# is in Mid−State, the undriven PWM pin will be set by its internal resistor network to its Mid-State voltage.

Disable Input (DISB#)

The DISB# pin is used to disable the High−Side MOSFET to prevent power transfer. The pin has a pull−down resistance to force a disabled state when it is left unconnected. DISB# can be driven from the output of a logic device or set high with a pull−up resistance to VCC.

AOZ5239QI

VCC Under-voltage Lockout

The VCC pin is monitored by an Under-voltage Lockout Circuit (UVLO). VCC voltage above the rising threshold enables the AOZ5239QI.

Table 4. UVLO/DISB# Logic

Thermal Warning / Thermal Shutdown Output

The THWN pin is an open drain output. When the temperature of the driver exceeds T_{THWN} Threshold (Temperature), the THWN pin will be pulled low indicating a thermal warning. At this point, the part continues to function normally. When the temperature drops in accordance to the $T_{HWN HYS}$, below T_{THWN} , the THWN pin will re-enter the open-drain output state. If the driver temperature exceeds T_{HDN} Temperature threshold, the part will enter thermal shutdown and turn off both upper and lower MOSFETs. Once the temperature falls in accordance to the $T_{HDN HYS}$, below T_{HDN} , the part will resume normal operation.

Skip Mode Input (SMOD#)

The SMOD# tri−state input pin has an internal pull−up resistance to VCC. When driven high, the SMOD# pin enables the low side synchronous MOSFET to operate independently of the internal ZCD function. When the SMOD# pin is set low during the PWM cycle it prioritizes control of the low side MOSFET to allow discontinuous mode operation. The AOZ5239QI has the capability of internally connecting a resistor divider to the PWM pin. To engage this mode, SMOD# needs to be placed into mid−state. While in SMOD# mid−state, the IC logic is equivalent to SMOD# being in the high state.

PCB Layout Guidelines

AOZ5239QI is a high current module rated for operation up to 2 MHz. This requires extremely fast switching speeds to keep the switching losses and device temperatures within limits. Having a robust gate driver integrated in the package eliminates driver-to-MOSFET gate pad parasitics of the package or PCB.

While excellent switching speeds are achieved, correspondingly high levels of dv/dt and di/dt will be observed throughout the power train which requires careful attention to PCB layout to minimize voltage spikes and other transients. As with any synchronous buck converter layout, the critical requirement is to minimize the area of the primary switching current loop, formed by the HS MOSFET, LS MOSFET and the input bypass capacitor Cin. The PCB design is somewhat simplified because of the optimized pin out in AOZ5239QI. The bulk of VIN and PGND pins are located adjacent to each other and the input bypass capacitors should be placed as close as possible to these pins. The area of the secondary switching loop, formed by LS MOSFET, output inductor and output capacitor Cout is the next critical parameter, this requires second layer or "Inner 1" should always be an uninterrupted GND plane with sufficient GND vias placed as close as possible to by-pass capacitors GND pads.

Figure 15. Top Layer of Demo Board, VIN, VSWH and PGND Copper Planes

As shown on Fig. 15, the top most layer of the PCB should comprise of copper flooding for the primary AC current loop that run along the VIN copper plane originating from the bypass capacitors which are mounted to a large PGND copper plane, also on the top most layer of the PCB. These copper planes also serve as heat dissipating elements as heat simply flows down to the VIN exposed pad and onto the top layer VIN copper plane which fans out to a wider area moving away from the 5x5 QFN package. Adding vias will only help transfer heat to cooler regions of the PCB board through the other layers beneath but serve no purpose to AC activity as all the AC current sees the lowest impedance on the top layer only

Due to the optimized bonding technique used on the AOZ5239QI internal package, the VIN input capacitors are optimally placed for AC current activities on both the primary and complimentary current loops. The return path of the current during the complimentary period flows through a non interrupted PGND copper plane that is symmetrically proportional to the VIN copper plane.

Due to the PGND exposed pad, heat is optimally dissipated simply by flowing down through the vertically structured lower MOSFET, through the exposed PGND pad and down to the PCB top layer PGND copper plane that also fans outward, moving away from the package.

As the primary and secondary (complimentary) AC current loops move through VIN to VSWH and through PGND to VSWH, large positive and negative voltage spikes appear at the VSWH terminal which are caused by the large internal dI/dts produced through the in package parastics. To minimize the effects of this interference, the VSWH terminal at which the main inductor L1 is mounted to, is sized just so the inductor can physically fit. The goal is to employ the least amount of copper area for this VSWH terminal just enough so the inductor can be securely mounted.

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Figure 16. Bottom Layer PCB Layout

The AOZ5239QI can be operated at a switching frequency of up to 2 MHz. This implies that the inherent capacitive parameters of the High Side and Low Side MOSFETs need to be charged and discharge on each and every cycle. Due to the AC currents flowing in and out of the Input Capacitors, the exposed pads (VIN and PGND) would tend to heat up, hence requiring thermal venting.

Positioning vias through the landing pattern of the VIN and PGND thermal pads will help quickly facilitate the thermal build up and spread the heat much more quickly towards the surrounding copper layers descending from the top layer. (See RECOMMENDED LANDING PATTERN AND VIA PLACEMENT section).

The exposed pads dimensional footprint of the 5x5 QFN package is shown on the package dimensions page. For optimal thermal relief, it is recommended to fill the PGND and VIN exposed landing pattern with 10mil diameter vias. 10mil diameter is a commonly used via diameter as it is optimally cost effective based on the tooling bit used in manufacturing. Each via is associated with a 20mil diameter keep out. Maintain a 5mil clearance (127um) around the inside edge of each exposed pad in an event of solder overflow, potentially shorting with the adjacent expose thermal pad.

Package Dimensions, QFN5x5A_31L EP3_S

Side View

Recommended Land Pattern Via Placements

NOTE CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

Tape and Reel Dimensions, QFN5x5A_31L_EP3_S

Carrier Tape

Reel

Leader/Trailer & Orientation

Part Marking

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